



Mini-Circuits

MMIC SURFACE MOUNT

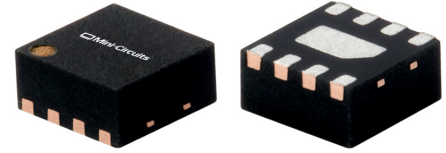
Low Noise Amplifier

TSS-23ULN+

50Ω 10 to 2000 MHz Shutdown Feature

THE BIG DEAL

- Low Noise Figure, Typ. 0.4 dB
- High Gain, Typ. 20 dB
- High OIP3, Typ. +37.3 dBm
- Fast Shutdown Feature, 7.5 ns
- Single Supply Voltage, +5 V at 70.6 mA
- 2x2 mm 8-Lead QFN-style Package

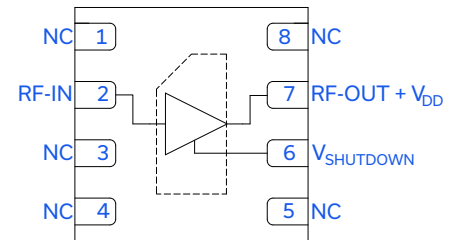


Generic photo used for illustration purposes only

APPLICATIONS

- Cellular Infrastructure
- Satellite Communications
- Radar, EW, and ECM Defense Systems

FUNCTIONAL DIAGRAM (TOP VIEW)



PRODUCT OVERVIEW

The TSS-23ULN+ is a pHEMT-based wideband, ultra-low noise MMIC amplifier with high P1dB, high IP3, and voltage-controlled shutdown capability. Operating from 10 to 2000 MHz, this amplifier features typical 0.4 dB noise figure, 20 dB gain, +20.3 dBm P1dB, and +37.3 dBm OIP3. This combination of characteristics makes it ideal for sensitive receiver applications. TSS-23ULN+ operates on a single +5 V supply and comes in a small, low profile, 2x2 mm QFN-style package for ease of integration into dense circuit board layouts.

KEY FEATURES

Features	Advantages
Ultra-Low Noise Figure, Typ. 0.4 dB	Operating from a single supply, this ultra-low noise MMIC enables low system noise figure performance, without the need for complicated discrete-based solutions.
High Gain, Typ. 20 dB	The MMIC amplifier's high gain enables fewer system components in receiver signal chains.
Shutdown Feature	A voltage-controlled shutdown feature allows the part to be quickly disabled to conserve power when not in use.
High Dynamic Range <ul style="list-style-type: none">• Gain, Typ. 20 dB• OIP3, Typ. +37.3 dBm• P1dB, Typ. +20.3 dBm	The MMIC amplifier's unique combination of low noise figure, high gain, high P1dB, and high OIP3 enables optimum performance in sensitive high dynamic range receivers.
2x2 mm 8-Lead QFN-Style Package	Small footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB. Industry standard packaging allows for ease of assembly in high volume manufacturing processes.

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ELECTRICAL SPECIFICATIONS¹ AT +25°C AND Z₀ = 50Ω UNLESS NOTED OTHERWISE

Parameter	Condition (MHz)	Amplifier - ON V _{DD} = +5 V (V _{SHUTDOWN} = 0 V)			Amplifier - ON V _{DD} = +3 V (V _{SHUTDOWN} = 0 V)	Amplifier - OFF V _{DD} = +5 V (V _{SHUTDOWN} = +5 V)	Units
		Min.	Typ.	Max.	Typ.	Typ.	
Frequency Range		10		2000	10-2000	10-2000	MHz
Gain	10	28.2	29.4		27.7	-21.3	dB
	500	23.6	24.7		23.5	-30.3	
	1000	18.9	20.0		18.9	-33.3	
	1500	15.7	16.9		15.9	-30.4	
	2000	13.3	14.5		13.6	-24.7	
Input Return Loss	10		9		7		dB
	500		13		10		
	1000		15		12		
	1500		16		13		
	2000		17		14		
Output Return Loss	10		20		19		dB
	500		14		16		
	1000		13		16		
	1500		12		15		
	2000		12		15		
Isolation	10-2000		26.5		25.4	30.2	dB
Output Power at 1dB Compression (P _{1dB})	10		+21.9		+16.8		dBm
	500		+20.4		+15.9		
	1000		+20.3		+15.8		
	1500		+19.2		+16.5		
	2000		+19.4		+16.2		
Output Third-Order Intercept Point (P _{OUT} = +4 dBm/Tone)	10		+34.3		+28.8		dBm
	500		+36.8		+28.0		
	1000		+37.3		+28.5		
	1500		+38.3		+28.7		
	2000		+36.1		+28.7		
Noise Figure ²	10		1.4		1.5		dB
	500		0.3		0.3		
	1000		0.4		0.3		
	1500		0.4		0.5		
	2000		0.5		0.4		
ON Time (50% V _{CTRL} to 90% RF)			9.5				ns
RISE Time (10% RF to 90% RF)			5.4				ns
FALL Time (90% RF to 10% RF)			6.2				ns
OFF Time (50% V _{CTRL} to 10% RF)			7.5				ns
Device Operating Voltage (V _{DD})		+2.7	5	+5.25	+3	+5	V
Device Operating Current (I _{DD}) ³			70.6		36.5	3	mA
Device Shutdown Voltage (V _{SHUTDOWN})			0		0	+5	V
Device Shutdown Current (I _{SHUTDOWN})			0.27		0.27	0.69	mA
Device Current Variation vs. Temperature ⁴			0.007		0.007		mA/°C
Device Current Variation vs. Voltage ⁵			0.0168		0.0168		mA/mV

1. Tested in Mini-Circuits Characterization Test/Evaluation Board TB-TSS-23ULNC+. See Figure 2. Board loss de-embedded to the device.

2. Typical value verified and set by averaging performance across multiple measurement setups.

3. Current at P_{IN} = -25 dBm. Increases to 90 mA at P_{1dB}.

4. (Current at +105°C - Current at -45°C) / (+150°C)

5. (Current at +5.25 V - Current at +4.75 V) / (+0.5 V)

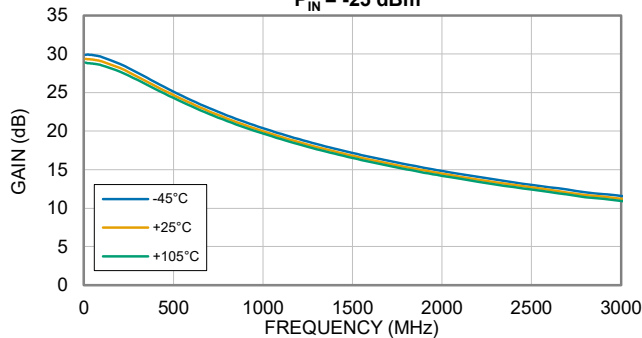




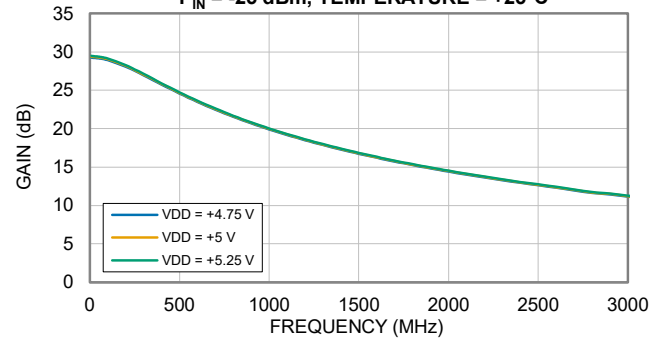
TYPICAL PERFORMANCE GRAPHS

Note: All data taken at nominal condition $V_{DD} = +5\text{ V}$ and $V_{SHUTDOWN} = 0\text{ V}$ unless noted otherwise.

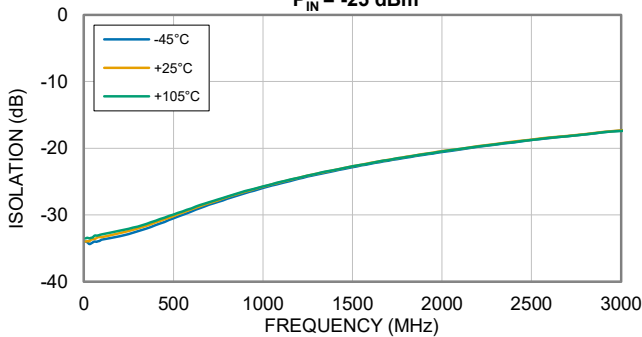
GAIN vs. TEMPERATURE
 $P_{IN} = -25\text{ dBm}$



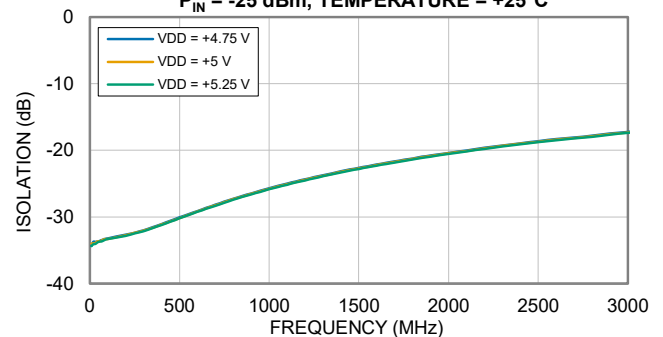
GAIN vs. DEVICE VOLTAGE (V_{DD})
 $P_{IN} = -25\text{ dBm}$, TEMPERATURE = $+25^\circ\text{C}$



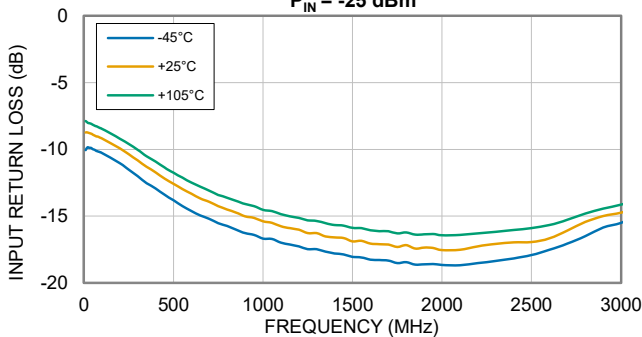
ISOLATION vs. TEMPERATURE
 $P_{IN} = -25\text{ dBm}$



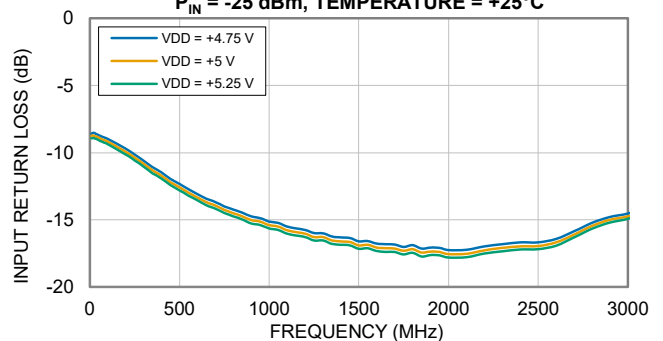
ISOLATION vs. DEVICE VOLTAGE (V_{DD})
 $P_{IN} = -25\text{ dBm}$, TEMPERATURE = $+25^\circ\text{C}$



INPUT RETURN LOSS vs. TEMPERATURE
 $P_{IN} = -25\text{ dBm}$



INPUT RETURN LOSS vs. DEVICE VOLTAGE (V_{DD})
 $P_{IN} = -25\text{ dBm}$, TEMPERATURE = $+25^\circ\text{C}$





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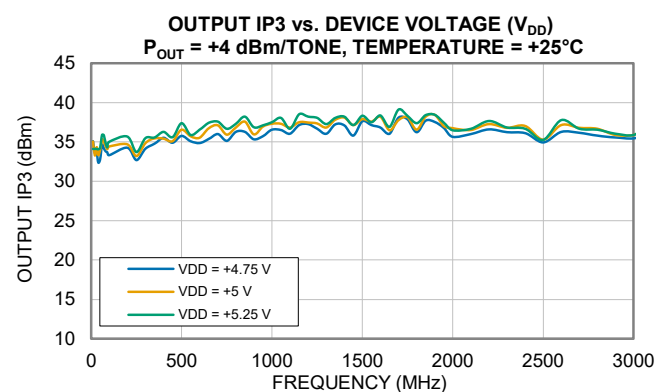
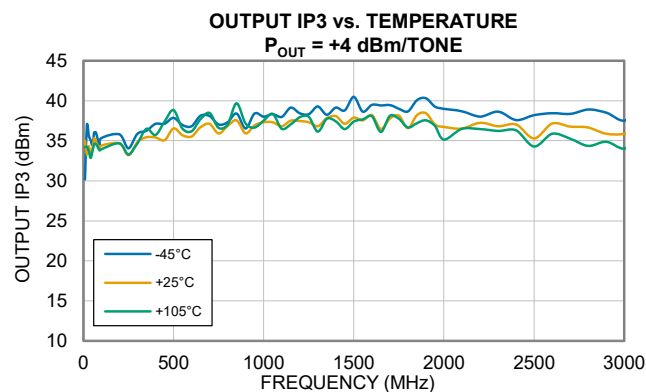
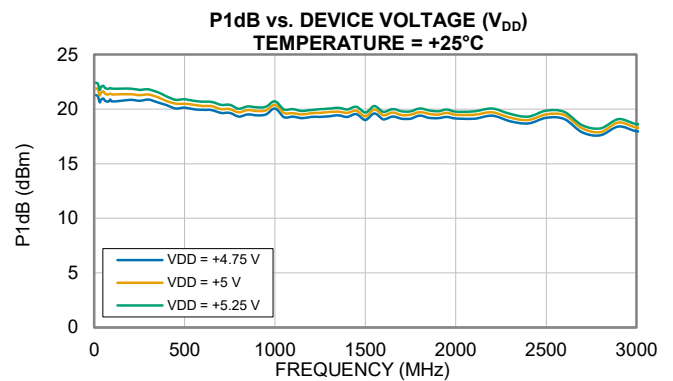
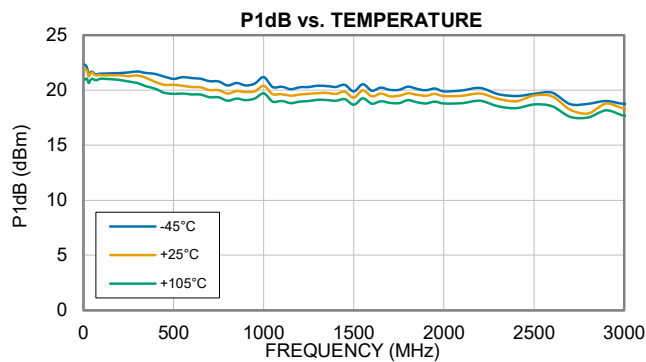
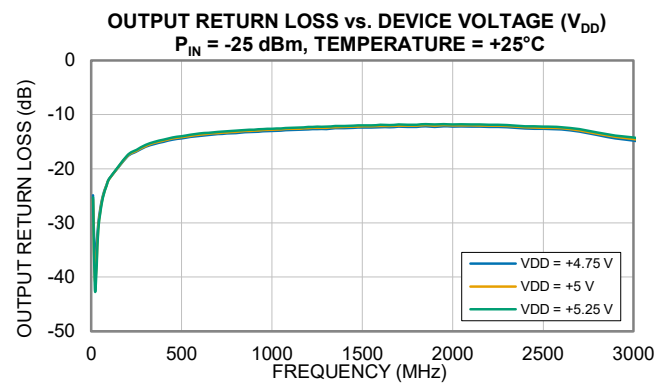
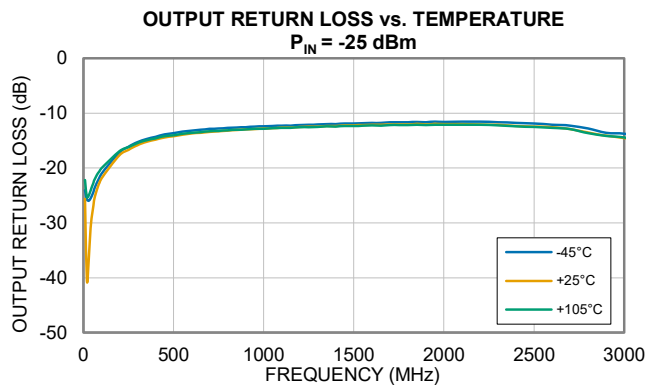
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Note: All data taken at nominal condition $V_{DD} = +5\text{ V}$ and $V_{SHUTDOWN} = 0\text{ V}$ unless noted otherwise.

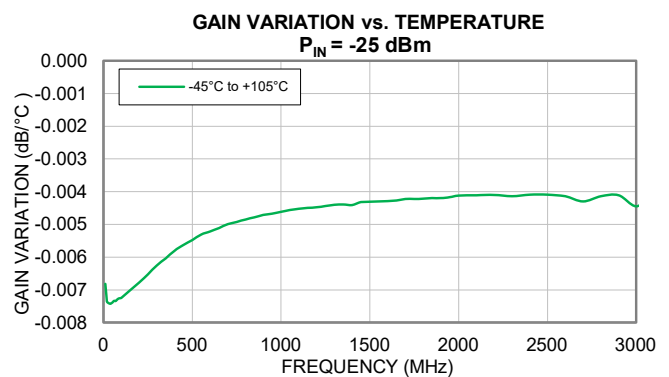
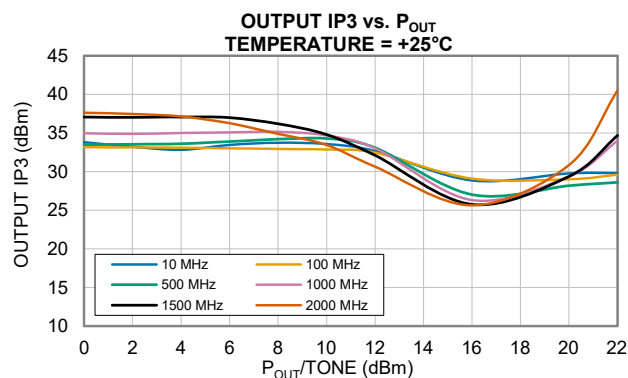
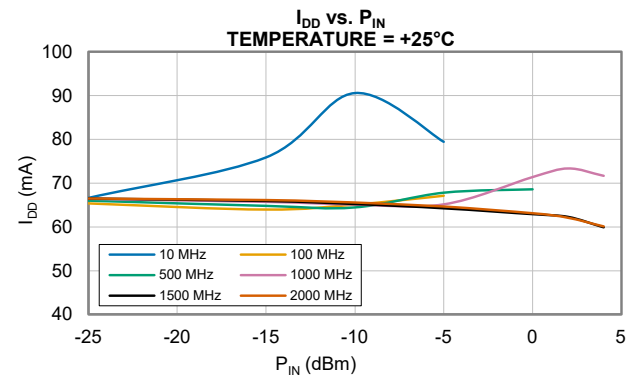
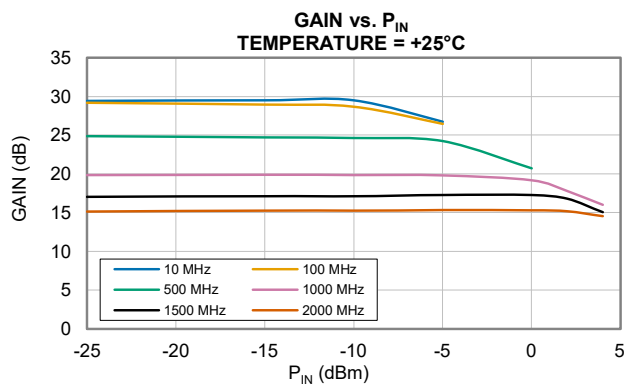
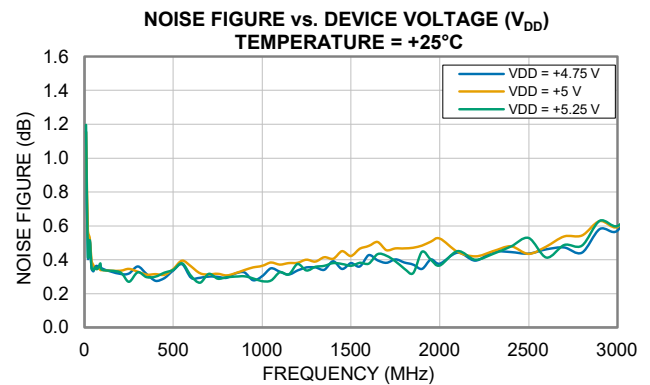
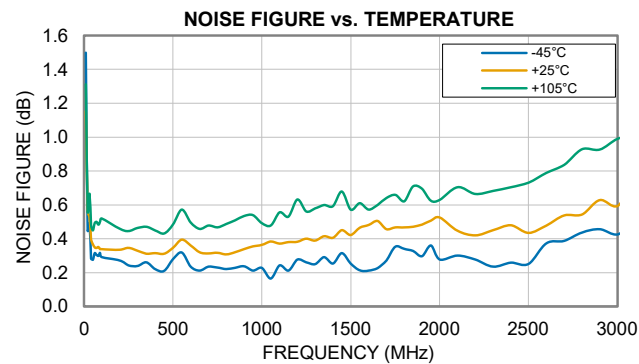


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TYPICAL PERFORMANCE GRAPHS

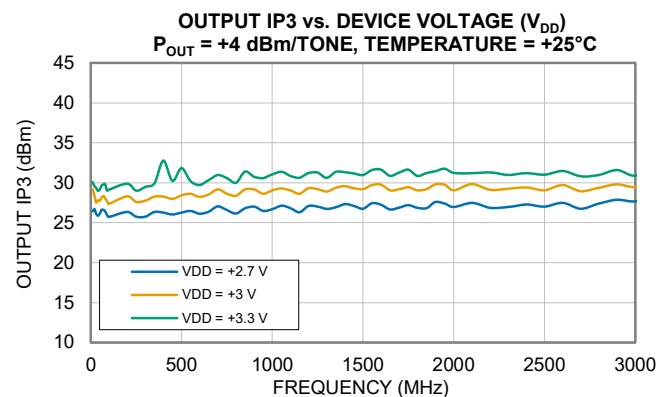
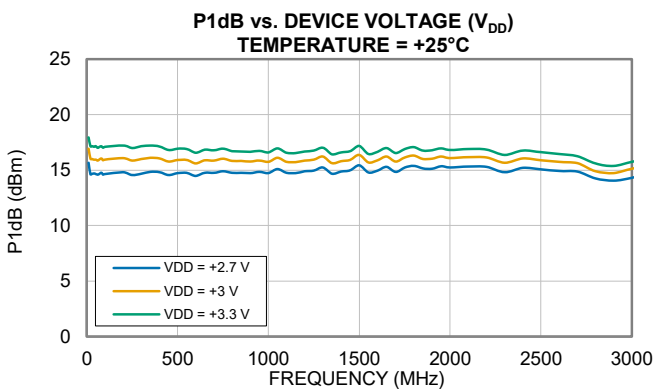
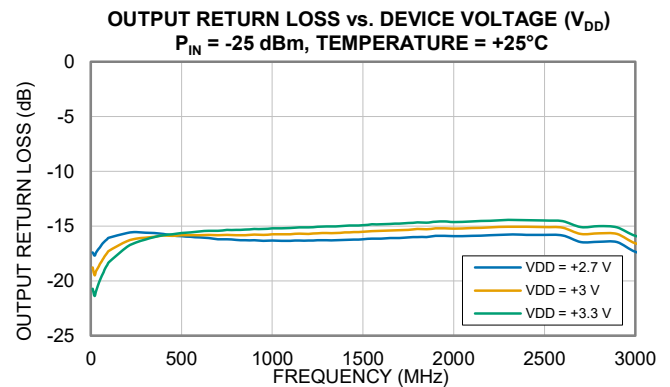
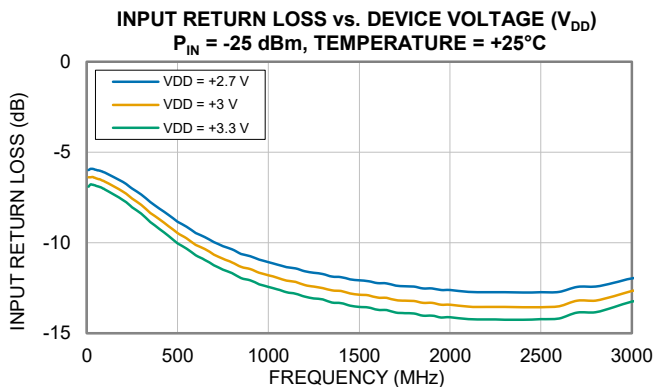
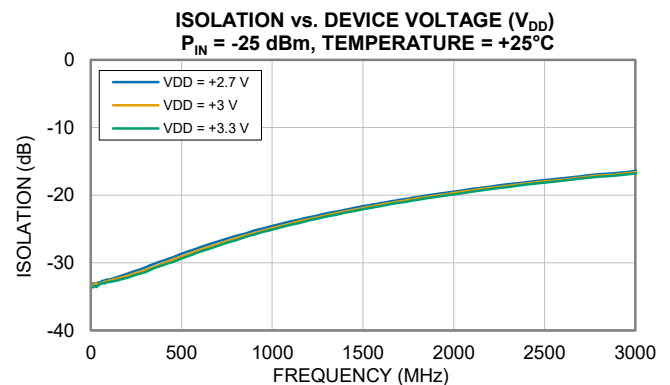
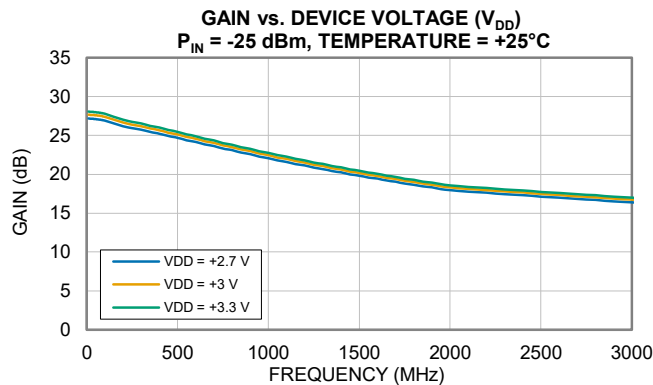
Note: All data taken at nominal condition $V_{DD} = +5\text{ V}$ and $V_{SHUTDOWN} = 0\text{ V}$ unless noted otherwise.





TYPICAL LOW VOLTAGE PERFORMANCE GRAPHS

Note: All data taken at nominal condition $V_{\text{SHUTDOWN}} = 0$ V unless noted otherwise.





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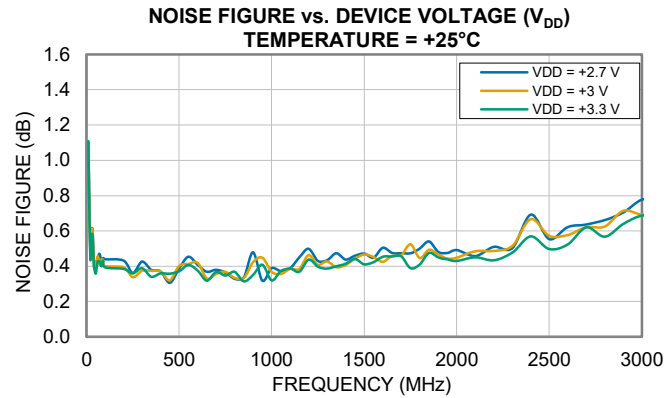
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Note: All data taken at nominal condition $V_{\text{SHUTDOWN}} = 0$ V unless noted otherwise.





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ABSOLUTE MAXIMUM RATINGS⁶

Parameter	Ratings
Operating Temperature	-45°C to +105°C
Storage Temperature	-65°C to +150°C
Total Power Dissipation	0.9 W
Junction Temperature ⁷	+150°C
Input Power (CW)	
$V_{DD} = +5\text{ V}$ & $V_{SHUTDOWN} = 0\text{ V}$	+21 dBm
$V_{DD} = +3\text{ V}$ & $V_{SHUTDOWN} = 0\text{ V}$	+21 dBm
DC Voltage on RF-OUT & V_{DD}	
$V_{SHUTDOWN} = 0\text{ V}$	+10 V
$V_{SHUTDOWN} = +5\text{ V}$	+10 V
DC Voltage on RF-IN	
$V_{SHUTDOWN} = 0\text{ V}$	+1 V
$V_{SHUTDOWN} = +5\text{ V}$	+1 V
DC Voltage on $V_{SHUTDOWN}$	
$V_{DD} = +5\text{ V}$	+10 V
$V_{DD} = +3\text{ V}$	+10 V
DC Current on RF-OUT & V_{DD}	
$V_{SHUTDOWN} = 0\text{ V}$	100 mA
$V_{SHUTDOWN} = +5\text{ V}$	10 mA
DC Current $V_{SHUTDOWN}$	
$V_{DD} = +5\text{ V}$	10 mA
$V_{DD} = +3\text{ V}$	10 mA

6. Permanent damage may occur if any of these limits are exceeded. Maximum ratings are not intended for continuous normal operation.

7. Peak temperature on top of Die.

POWER ON / POWER OFF LOGIC

Amplifier State	V_{DD}			$V_{SHUTDOWN}$		
	Min	Typ.	Max	Min	Typ.	Max
Amplifier – ON ($V_{DD} = +5\text{ V}$)	+2.7 V	+5 V	+5.25 V	0 V	0 V	+1.3 V
Amplifier – OFF ($V_{DD} = +5\text{ V}$)				+1.4 V	+5 V	+5.25 V
Amplifier – ON ($V_{DD} = +3\text{ V}$)	+2.7 V	+3 V	+5.25 V	0 V	0 V	+1.3 V
Amplifier – OFF ($V_{DD} = +3\text{ V}$)				+1.4 V	+3 V	+5.25 V

THERMAL RESISTANCE

Parameter	Ratings
Thermal Resistance (Θ_{JC}) ⁸	48.7°C/W

8. Θ_{JC} = (Hot Spot Temperature on Die - Temperature at Ground Lead)/Dissipated Power

ESD RATING

	Class	Voltage Range	Reference Standard
HBM	1A	250 V to < 500 V	ANSI/ESDA/JEDEC JS-001-2023
CDM	C3	> 1000 V	ANSI/ESDA/JEDEC JS-002-2022



ESD HANDLING PRECAUTION: This device is designed to be Class 1A for HBM. Static charges may easily produce potentials higher than this with improper handling and can discharge into DUT and damage it. As a preventive measure Industry standard ESD handling precautions should be used at all times to protect the device from ESD damage.

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020E /JEDEC J-STD-033C

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FUNCTIONAL DIAGRAM

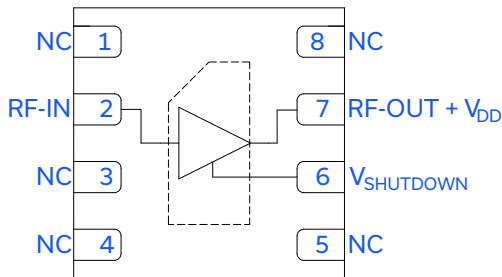


Figure 1. TSS-23ULN+ Functional Diagram

PAD DESCRIPTION

Function	Pad Number	Description (Refer to Figure 2)
RF-OUT + V_{DD}	7	RF-OUT + V_{DD} Pad connects to RF-Output port and voltage input port, V_{DD} .
$V_{SHUTDOWN}$	6	DC Input Pad connects to voltage input port, $V_{SHUTDOWN}$.
RF-IN	2	RF-IN Pad connects to RF Input port.
NC	1, 3-5, and 8	Not used internally. May be connected to ground or left floating. Grounded on evaluation board.
GND	Paddle	Connects to ground.

EVALUATION BOARD

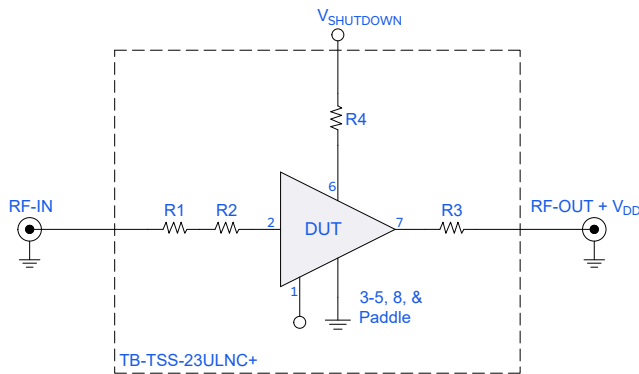


Figure 2. TSS-23ULN+ Evaluation and Application Circuit

Electrical Parameters and Conditions

Gain, Return Loss, Output Power at 1 dB Compression (P1dB), Output IP3 (OIP3), and Noise Figure measured using N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return Loss: $P_{IN} = -25$ dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, +4 dBm/tone at output.

Power ON/Power OFF Sequence:

Caution: Permanent damage to the device will occur if the Power ON and Power OFF sequences are not followed.

POWER ON:

1. Set $V_{SHUTDOWN} = 0$ V for ON mode or $V_{SHUTDOWN} = +5$ V for OFF mode.
2. Set $V_{DD} = +5$ V.
3. Turn on $V_{SHUTDOWN}$.
4. Turn on V_{DD} .

POWER OFF:

1. Turn off RF signal.
2. Turn off V_{DD} .
3. Turn off $V_{SHUTDOWN}$.

Component	Size	Value	Part Number	Manufacturer
R1-R4	0402	0Ω	RK73Z1ETTP	KOA Speer





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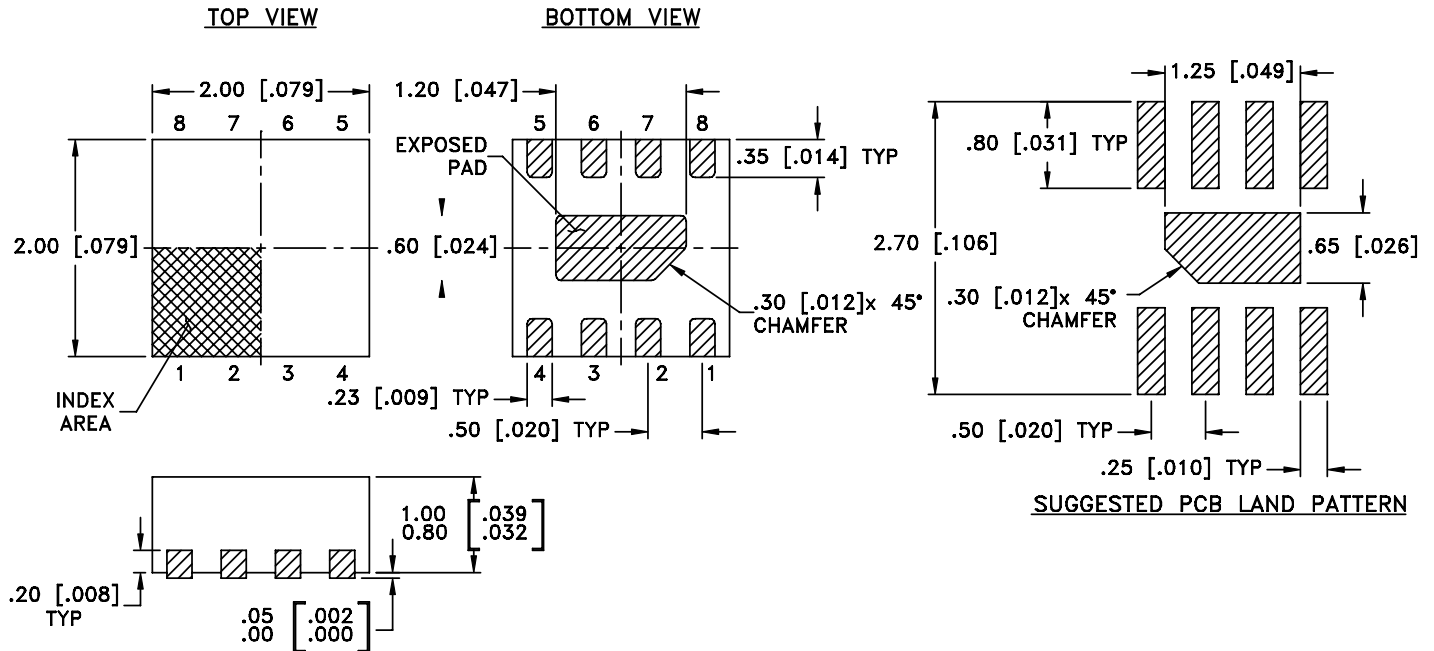
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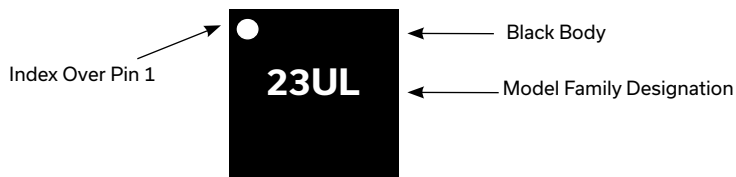
CASE STYLE DRAWING



Weight: 0.006 grams

Dimensions are in mm [Inches]. Tolerances: 2Pl. +/- 0.256 [0.01]; 3 Pl. 0.127 [0.005] mm [inches]

PRODUCT MARKING



Marking may contain other features or characters for internal lot control.

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www.minicircuits.com P.O. Box 350166, Brooklyn, NY 11235-0003 (718) 934-4500 sales@minicircuits.com

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ADDITIONAL DETAILED INFORMATION IS AVAILABLE ON OUR DASHBOARD

[CLICK HERE](#)

Performance Data & Graphs	Data Graphs S-Parameter (S2P Files) Data Set (.zip file)
Case Style	MC1631-1. Plastic package, exposed paddle, Lead Finish: Matte-Tin
RoHS Status	Compliant
Tape & Reel Standard Quantities Available on Reel	F66 7" Reels with 20, 50, 100, 200, 500, 1000, 2000, or 3000 devices
Suggested Layout for PCB Design	PL-815
Evaluation Board	TB-TSS-23ULNC+ Gerber File
Environmental Ratings	ENV08T1

NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuits' applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html

